

TLP250

Transistor Inverter

Inverter For Air Conditioner

IGBT Gate Drive

Power MOS FET Gate Drive

The TOSHIBA TLP250 consists of a GaAlAs light emitting diode and a integrated photodetector.

This unit is 8-lead DIP package.

TLP250 is suitable for gate driving circuit of IGBT or power MOS FET.

- Input threshold current: $I_F=5\text{mA}(\text{max.})$
- Supply current (I_{CC}): $11\text{mA}(\text{max.})$
- Supply voltage (V_{CC}): $10\sim 35\text{V}$
- Output current (I_O): $\pm 1.5\text{A}(\text{max.})$
- Switching time (t_{pLH}/t_{pHL}): $0.5\mu\text{s}(\text{max.})$
- Isolation voltage: $2500V_{\text{rms}}(\text{min.})$
- UL recognized: UL1577, file No.E67349
- Option(D4)

VDE Approved : DIN EN60747-5-2

Maximum Operating Insulation Voltage : $890V_{\text{PK}}$

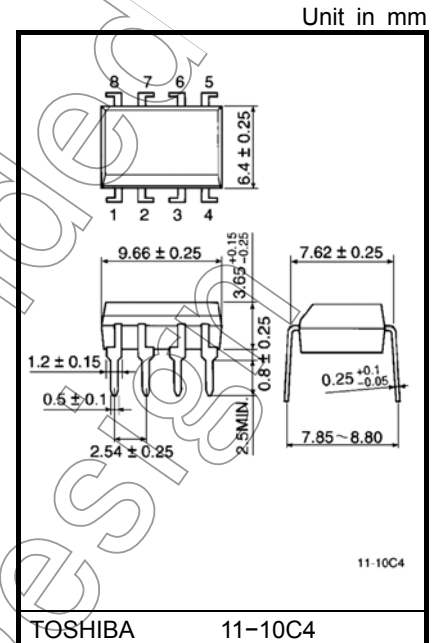
Highest Permissible Over Voltage : $4000V_{\text{PK}}$

(Note):When a EN60747-5-2 approved type is needed,

Please designate "Option(D4)"

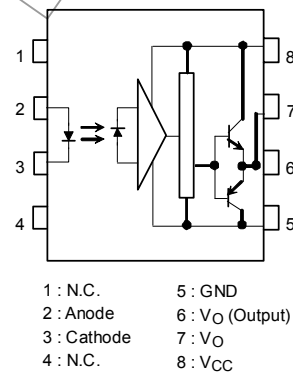
Truth Table

Input LED		Tr1		Tr2	
		On	Off	On	Off
On		On	Off	Off	On
Off		Off	On	On	Off

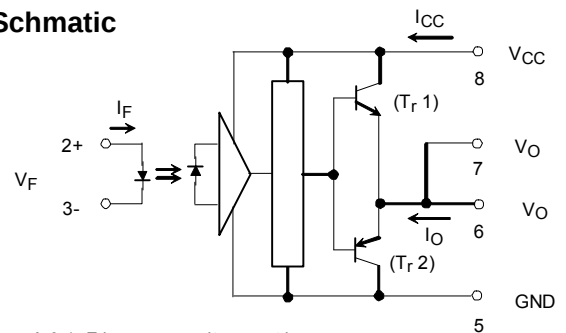


Weight: 0.54 g (typ.)

Pin Configuration (top view)



Schematic



Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	20	mA
	Forward current derating (Ta ≥ 70°C)	$\Delta I_F / \Delta T_a$	-0.36	mA / °C
	Peak transient forward current (Note 1)	I_{FPT}	1	A
	Reverse voltage	V_R	5	V
	Junction temperature	T_j	125	°C
Detector	"H" peak output current ($P_W \leq 2.5\mu s, f \leq 15\text{kHz}$) (Note 2)	I_{OPH}	-1.5	A
	"L" peak output current ($P_W \leq 2.5\mu s, f \leq 15\text{kHz}$) (Note 2)	I_{OPL}	+1.5	A
	Output voltage	V_O	35	V
			24	
	Supply voltage	V_{CC}	35	V
			24	
	Output voltage derating (Ta ≥ 70°C)	$\Delta V_O / \Delta T_a$	-0.73	V / °C
	Supply voltage derating (Ta ≥ 70°C)	$\Delta V_{CC} / \Delta T_a$	-0.73	V / °C
	Junction temperature	T_j	125	°C
Operating frequency (Note 3)		f	25	kHz
Operating temperature range		T_{opr}	-20~85	°C
Storage temperature range		T_{stg}	-55~125	°C
Lead soldering temperature (10 s)		T_{sol}	260	°C
Isolation voltage (AC, 1 min., R.H. ≤ 60%) (Note 4)		BV_S	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width $P_W \leq 1\mu s$, 300pps

Note 2: Exponential waveform

Note 3: Exponential waveform, $I_{OPH} \leq -1.0A (\leq 2.5\mu s)$, $I_{OPL} \leq +1.0A (\leq 2.5\mu s)$

Note 4: Device considered a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.

Note 5: A ceramic capacitor(0.1μF) should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1cm.

Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Input current, on (Note6)	$I_{F(ON)}$	7	8	10	mA
Input voltage, off	$V_{F(OFF)}$	0	—	0.8	V
Supply voltage	V_{CC}	15	—	30 20	V
Peak output current	I_{OPH}/I_{OPL}	—	—	±0.5	A
Operating temperature	T_{opr}	-20	25	70 85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 6: Input signal rise time(fall time) < 0.5μs.

Electrical Characteristics (Ta = -20~70°C, unless otherwise specified)

Characteristic		Symbol	Test Circuit	Test Condition		Min	Typ.*	Max	Unit
Input forward voltage		V _F	—	I _F = 10 mA, Ta = 25°C		—	1.6	1.8	V
Temperature coefficient of forward voltage		ΔV _F / ΔTa	—	I _F = 10 mA		—	-2.0	—	mV / °C
Input reverse current		I _R	—	V _R = 5V, Ta = 25°C		—	—	10	μA
Input capacitance		C _T	—	V = 0, f = 1MHz, Ta = 25°C		—	45	250	pF
Output current	"H" level	I _{OPH}	1	V _{CC} = 30V (*1)	I _F = 10 mA V ₈₋₆ = 4V	-0.5	-1.5	—	A
	"L" level	I _{OPL}	2		I _F = 0 V ₆₋₅ = 2.5V	0.5	2	—	
Output voltage	"H" level	V _{OH}	3	V _{CC1} = +15V, V _{EE1} = -15V R _L = 200Ω, I _F = 5mA		11	12.8	—	V
	"L" level	V _{OL}	4	V _{CC1} = +15V, V _{EE1} = -15V R _L = 200Ω, V _F = 0.8V		—	-14.2	-12.5	
Supply current	"H" level	I _{CCH}	—	V _{CC} = 30V, I _F = 10mA Ta = 25°C		—	7	—	mA
				V _{CC} = 30V, I _F = 10mA		—	—	11	
	"L" level	I _{CCL}	—	V _{CC} = 30V, I _F = 0mA Ta = 25°C		—	7.5	—	
				V _{CC} = 30V, I _F = 0mA		—	—	11	
Threshold input current	"Output L→H"	I _{FLH}	—	V _{CC1} = +15V, V _{EE1} = -15V R _L = 200Ω, V _O > 0V		—	1.2	5	mA
Threshold input voltage	"Output H→L"	V _{FHL}	—	V _{CC1} = +15V, V _{EE1} = -15V R _L = 200Ω, V _O < 0V		0.8	—	—	V
Supply voltage		V _{CC}	—			10	—	35	V
Capacitance (input-output)		C _S	—	V _S = 0, f = 1MHz Ta = 25°C		—	1.0	2.0	pF
Resistance(input-output)		R _S	—	V _S = 500V, Ta = 25°C R.H. ≤ 60%		1×10 ¹²	10 ¹⁴	—	Ω

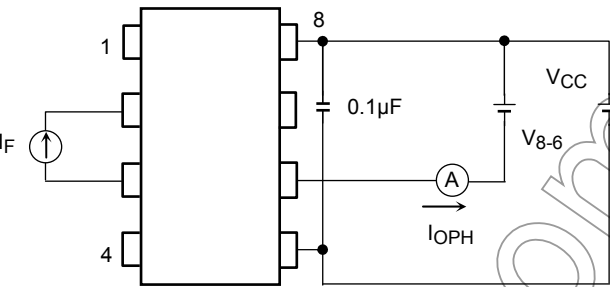
* All typical values are at Ta = 25°C (*1): Duration of I_O time ≤ 50μs

Switching Characteristics (Ta = -20~70°C , unless otherwise specified)

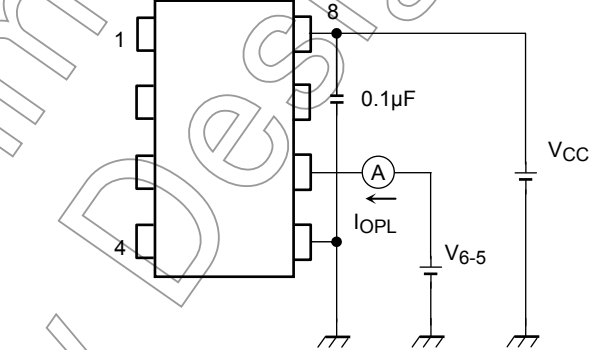
Characteristic		Symbol	Test Cir-cuit	Test Condition	Min	Typ.*	Max	Unit
Propagation delay time	L→H	t _{pLH}	5	I _F = 8mA V _{CC1} = +15V, V _{EE1} = -15V R _L = 200Ω	—	0.15	0.5	μs
	H→L	t _{pHL}			—	0.15	0.5	
Output rise time		t _r			—	—	—	
Output fall time		t _f			—	—	—	
Common mode transient immunity at high level output		C _{MH}	6	V _{CM} = 600V, I _F = 8mA V _{CC} = 30V, Ta = 25°C	-5000	—	—	V / μs
Common mode transient immunity at low level output		C _{ML}		V _{CM} = 600V, I _F = 0mA V _{CC} = 30V, Ta = 25°C	5000	—	—	V / μs

All typical values are at Ta = 25°C

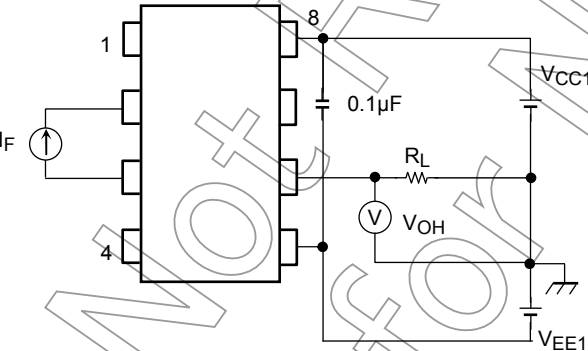
Test Circuit 1 : I_{OPH}



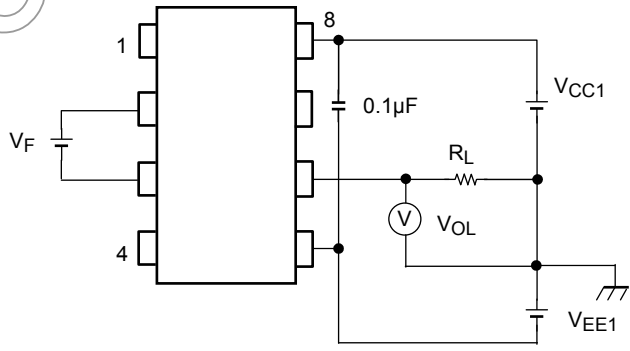
Test Circuit 2: I_{OPL}



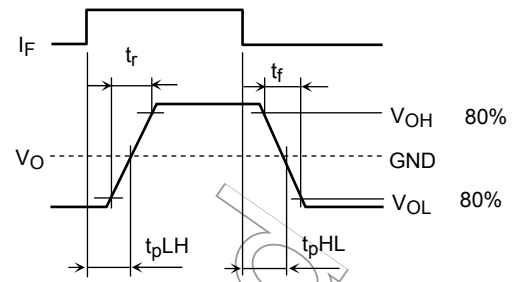
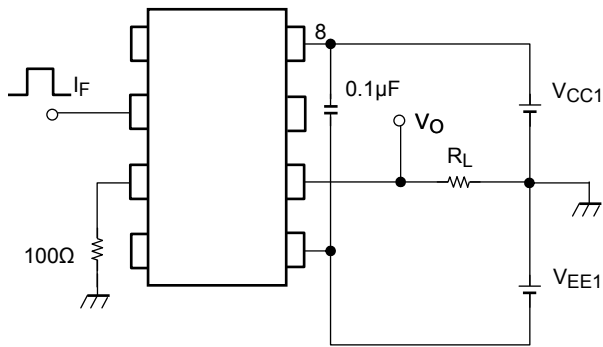
Test Circuit 3 : V_{OH}



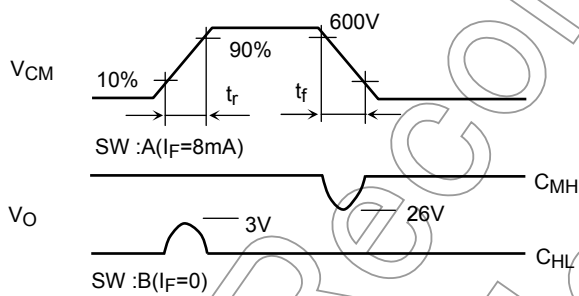
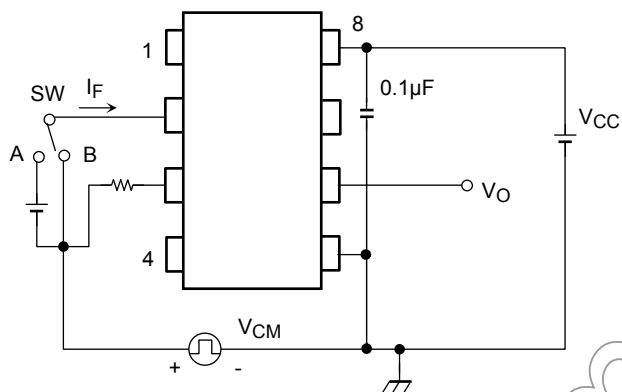
Test Circuit 4 : V_{OL}



Test Circuit 5: t_{pLH} , t_{pHL} , t_r , t_f



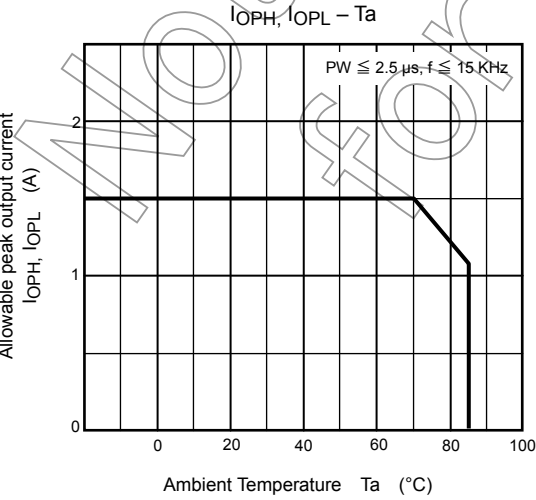
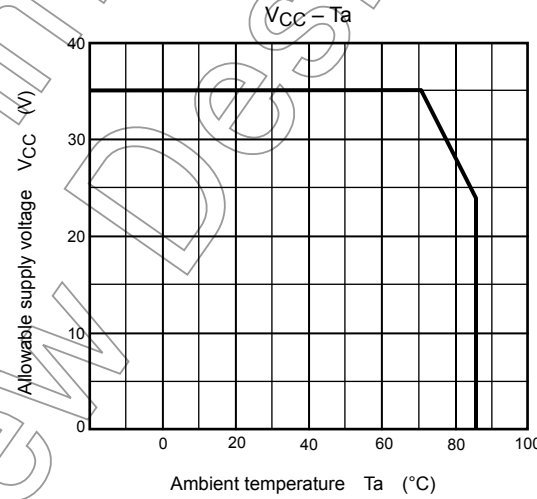
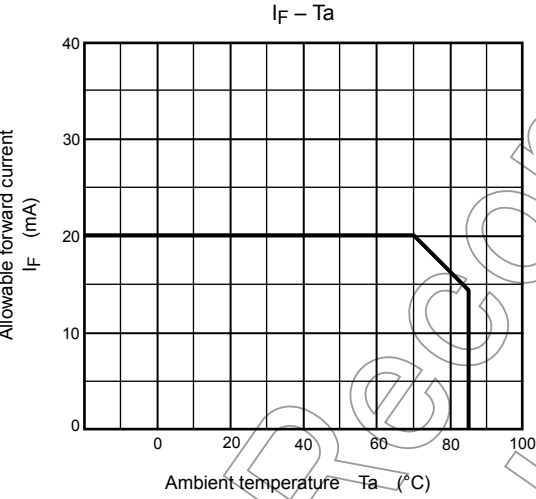
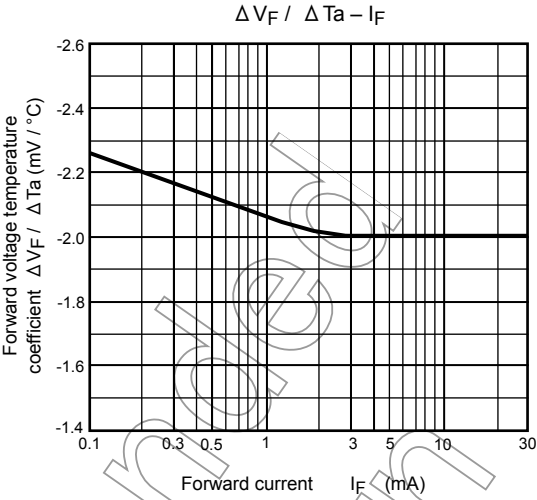
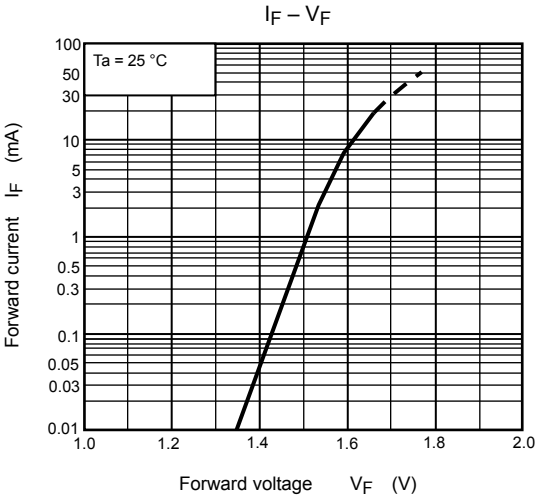
Test Circuit 6: C_{MH} , C_{ML}



$$C_{ML} = \frac{480 (V)}{t_r (\mu s)}$$

$$C_{MH} = \frac{480 (V)}{t_f (\mu s)}$$

$C_{ML}(C_{MH})$ is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.



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Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.